



**DMN3110SQ** 

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	73mΩ @ V <sub>GS</sub> = 10V	3.3A
30V	110mΩ @ V <sub>GS</sub> = 4.5V	2.7A

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- General Purpose Interfacing Switch
- **Power Management Functions**
- **Boost Application**
- Analog Switch

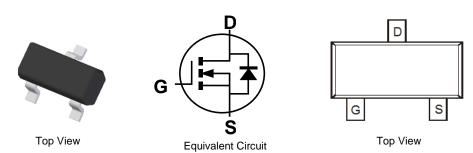
## N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.027 grams (Approximate)



#### Ordering Information (Note 5)

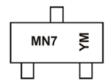
	Part Number	Case	Packaging				
	DMN3110SQ-7	SOT23	3000/Tape & Reel				
Notes:	1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS). 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



MN7 = Product Type Marking Code Y or  $\overline{Y}$  = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2007	~	2018	2019	202	20 20	)21	2022	2023	2024	2025	2026
Code	U	~	F	G	Н			J	K	L	М	N
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	30	V	
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	2.5 2.0	А
Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	3.3 2.7	А
Continuous Drain Current (Note 7) $V_{GS}$ = 10V	t≦10sec	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	3.8 3.1	A
Continuous Drain Current (Note 7) $V_{GS}$ = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	2.7 2.1	A
Pulsed Drain Current (Note 8)			I <sub>DM</sub>	25	A

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	0.74	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	173.4	°C/W
Total Power Dissipation (Note 7)	PD	1.3	W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>0JA</sub>	99.1	°C/W
Total Power Dissipation (Note 7) t≦10sec	PD	1.8	W
Thermal Resistance, Junction to Ambient (Note 7) t $\leq$ 10sec	R <sub>0JA</sub>	72	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

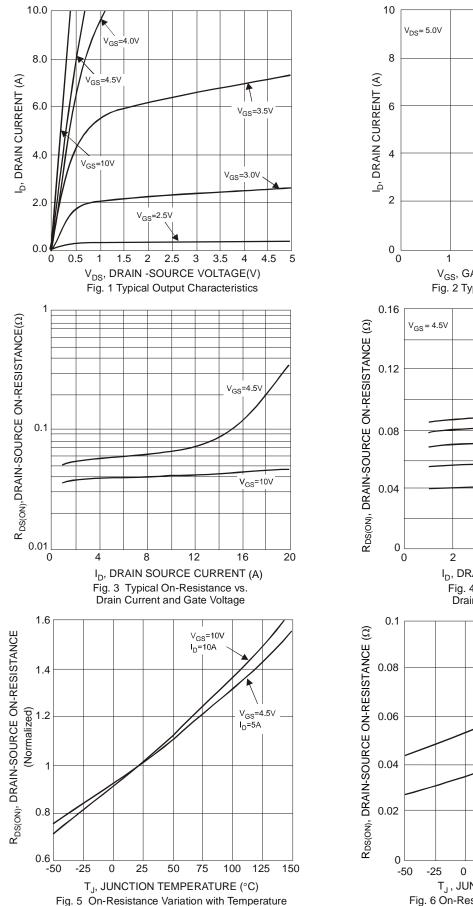
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)	I `	Cymbol		Typ	Mux	onit	
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	30	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current @	T <sub>C</sub> = +25°C	IDSS	-	-	1.0	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage		I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage		V <sub>GS(TH)</sub>	1.0	-	3.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance			-	54	73	mΩ	$V_{GS} = 10V, I_D = 3.1A$
		R <sub>DS(ON)</sub>	-	88	110	11122	$V_{GS} = 4.5V, I_D = 2A$
Forward Transfer Admittance		Y <sub>fs</sub>	-	4.8	-	mS	$V_{DS} = 10V, I_D = 3.1A$
Diode Forward Voltage (Note 7)		V <sub>SD</sub>	-	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance		Ciss	-	305.8	-	pF	
Output Capacitance		Coss	-	39.9	-	рF	−V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, −f = 1.0MHz
Reverse Transfer Capacitance		Crss	-	39.5	-	рF	1 = 1.000112
Gate Resistance		Rg	-	1.4	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)		Qg	-	4.1	-	nC	
Total Gate Charge (V <sub>GS</sub> = 10V)		Qg	-	8.6	-	nC	V 10V 1 20
Gate-Source Charge		Q <sub>gs</sub>	-	1.2	-	nC	$V_{DS} = 10V, I_D = 3A$
Gate-Drain Charge		Q <sub>gd</sub>	-	1.5	-	nC	
Turn-On Delay Time		t <sub>D(ON)</sub>	-	2.6	-	ns	
Turn-On Rise Time		t <sub>R</sub>	-	4.6	-	ns	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 10V,
Turn-Off Delay Time		t <sub>D(OFF)</sub>	-	13.1	-	ns	$R_L = 47\Omega, R_G = 3\Omega$
Turn-Off Fall Time		t <sub>F</sub>	-	2.5	-	ns	

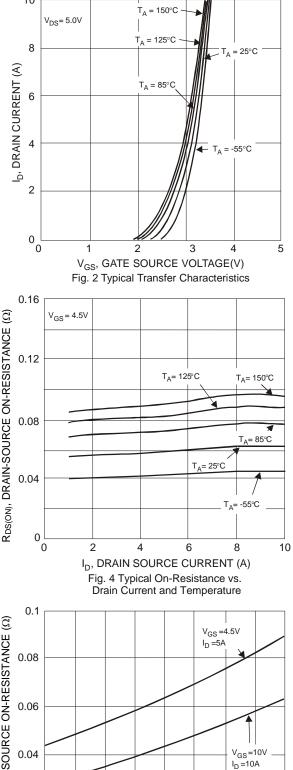
Notes:

6. Device mounted on FR-4 PCB, with minimum recommended pad layout.
7. Device mounted on FR-4 substrate PC board, 2oz copper, on 1inch square copper plate.
8. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%
9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.



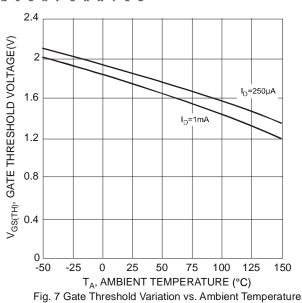
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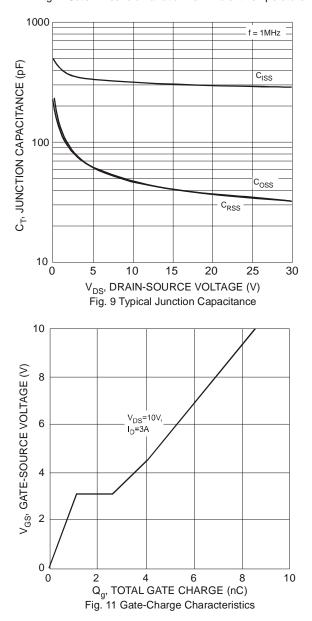


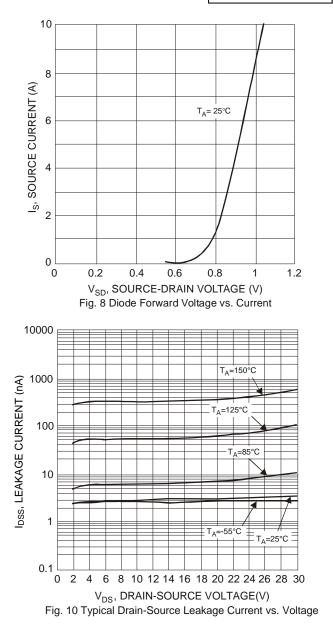




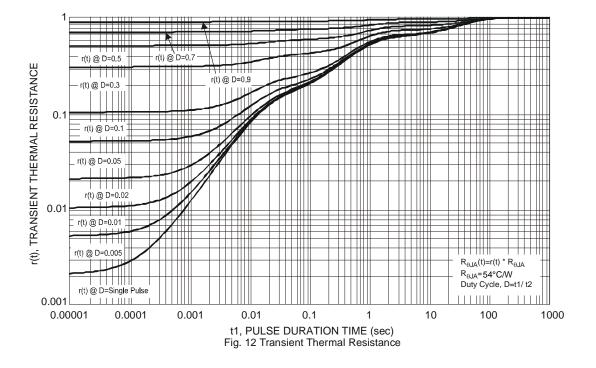






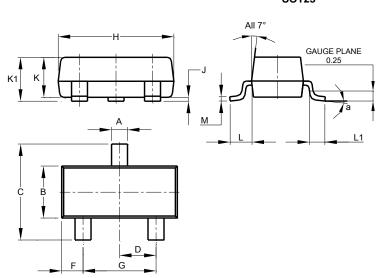






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



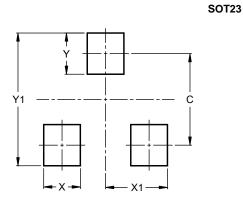
	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
Н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
K	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
Μ	0.085	0.150	0.110						
а	0°	8°							
All	Dimens	ions in	mm						

SOT23



#### Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

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